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April 1st, 2010 Renesas Electronics Corporation

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DATA SHEET

MOS FIELD EFFECT TRANSISTOR μ PA2717AGR

SWITCHING P-CHANNEL POWER MOS FET

DESCRIPTION

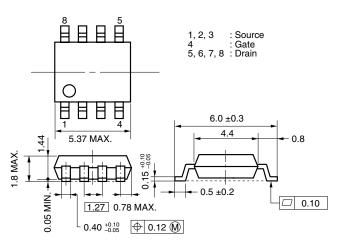
The μ PA2717AGR is P-Channel MOS Field Effect Transistor designed for power management applications of notebook computers and Lithium-Ion battery protection circuit.

FEATURES

- Low on-state resistance
- $\begin{aligned} R_{DS(on)1} &= 5.5 \text{ m}\Omega \text{ MAX. (Vgs} = -10 \text{ V, Id} = -7.5 \text{ A}) \\ R_{DS(on)2} &= 8.9 \text{ m}\Omega \text{ MAX. (Vgs} = -4.5 \text{ V, Id} = -7.5 \text{ A}) \end{aligned}$
- Low input capacitance
- Ciss = 3550 pF TYP.
- Built-in gate protection diode
- Small and surface mount package (Power SOP8)

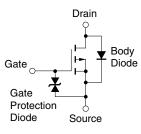
ABSOLUTE MAXIMUM RATINGS (TA = 25°C, All terminals are connected.)

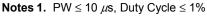
				,
Drain to Source Voltage (VGs = 0 V)	VDSS	-30	V	
Gate to Source Voltage (VDs = 0 V)	Vgss	∓20	V	E
Drain Current (DC)	D(DC)	∓15	А	
Drain Current (pulse) Note1	D(pulse)	∓150	А	
Total Power Dissipation Note2	P _{T1}	2	W	
Total Power Dissipation Note3	Pt2	2	W	
Channel Temperature	Tch	150	°C	
Storage Temperature	Tstg	-55 to +150	°C	
Single Avalanche Current Note4	las	-15	А	
Single Avalanche Energy Note4	Eas	22.5	mJ	



PACKAGE DRAWING (Unit: mm)

EQUIVALENT CIRCUIT





- **2.** Mounted on ceramic substrate of 1200 mm^2 x 2.2 mm
- 3. Mounted on glass epoxy board of 1 inch x 1 inch x 0.8 mm, PW = 10 sec
- 4. Starting T_{ch} = 25°C, V_{DD} = -15 V, R_G = 25 Ω , L = 100 μ H, V_{GS} = $-20 \rightarrow 0$ V
- **Remark** The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	$V_{DS} = -30 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			-1	μA
Gate Leakage Current	Igss	$V_{GS} = \mp 20 \text{ V}, V_{DS} = 0 \text{ V}$			∓10	μA
Gate to Source Cut-off Voltage	V _{GS(off)}	V _{DS} = -10 V, I _D = -1 mA	-1.0		-2.5	V
Forward Transfer Admittance Note	y _{fs}	V _{DS} = -10 V, I _D = -7.5 A	13			S
Drain to Source On-state Resistance Note	RDS(on)1	V _{GS} = -10 V, I _D = -7.5 A		4.7	5.5	mΩ
	RDS(on)2	$V_{GS} = -4.5 \text{ V}, \text{ I}_{D} = -7.5 \text{ A}$		6.1	8.9	mΩ
	RDS(on)3	$V_{GS} = -4.0 \text{ V}, \text{ I}_{D} = -7.5 \text{ A}$		6.9	10.4	mΩ
Input Capacitance	Ciss	V _{DS} = -10 V		3550		pF
Output Capacitance	Coss	V _{GS} = 0 V		1260		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		600		pF
Turn-on Delay Time	td(on)	V _{DD} = -15 V, I _D = -7.5 A		17		ns
Rise Time	tr	V _{GS} = -10 V		32		ns
Turn-off Delay Time	td(off)	R _G = 10 Ω		920		ns
Fall Time	tr			510		ns
Total Gate Charge	QG	V _{DD} = -24 V		130		nC
Gate to Source Charge	QGS	V _{GS} = -10 V		11		nC
Gate to Drain Charge	Qgd	I _D = -15 A		36		nC
Body Diode Forward Voltage Note	VF(S-D)	IF = 15 A, VGS = 0 V		0.82		V
Reverse Recovery Time	trr	IF = 15 A, VGS = 0 V		500		ns
Reverse Recovery Charge	Qrr	di/dt = 50 A/ <i>µ</i> s		1320		nC

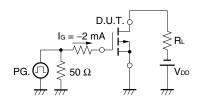
ELECTRICAL CHARACTERISTICS (T_A = 25°C, All terminals are connected.)

Note Pulsed

TEST CIRCUIT 1 AVALANCHE CAPABILITY

$PG. \bigcirc So \Omega \\ V_{GS} = -20 \rightarrow 0 V \\ \downarrow DD \\ \downarrow$

TEST CIRCUIT 3 GATE CHARGE



TEST CIRCUIT 2 SWITCHING TIME

≶r∟ 1

D.U.T.

Rg

PG.

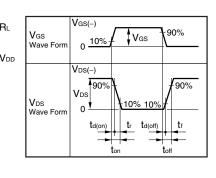
Vgs(-)

0

τ

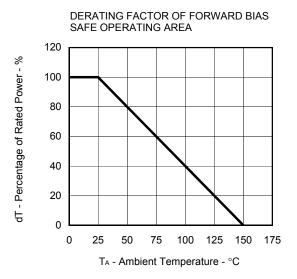
, Duty Cycle ≤ 1%

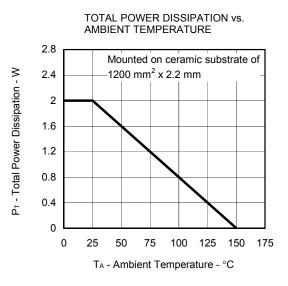
 $\tau = 1 \, \mu s$



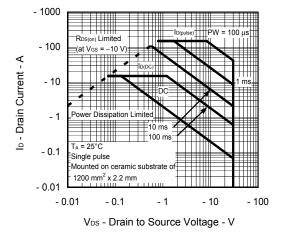
Data Sheet G19279EJ1V0DS

TYPICAL CHARACTERISTICS (TA = 25°C)

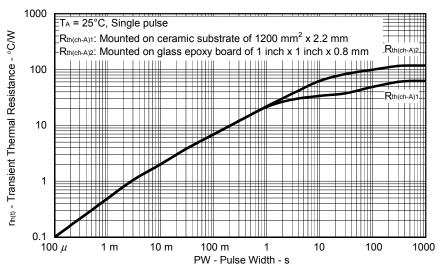




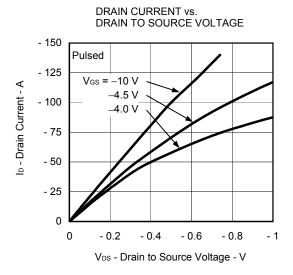
FORWARD BIAS SAFE OPERATING AREA



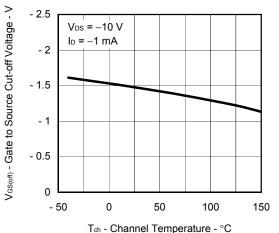
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

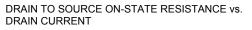


Data Sheet G19279EJ1V0DS

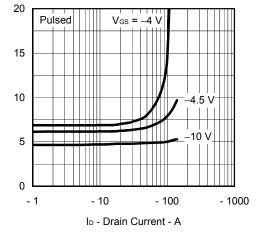


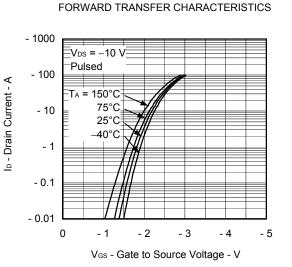




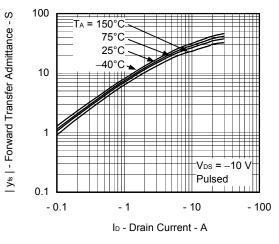




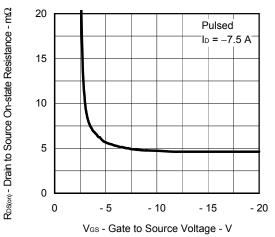




FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



Data Sheet G19279EJ1V0DS

10000

1000

100

10

1

-0.1

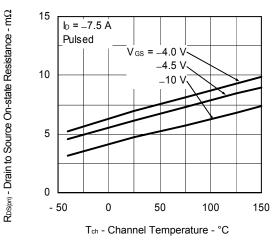
ta(on), tr, ta(off), tr - Switching Time - ns

VDD = -15 V

Vgs = -10 V R_G = 10 Ω

 $++\Pi$

-1



SWITCHING CHARACTERISTICS

.td(off)

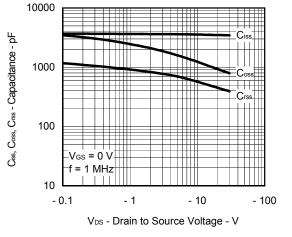
tı

tr

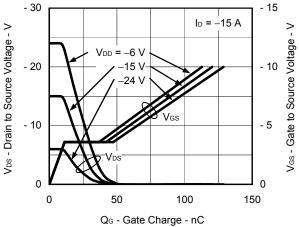
-100

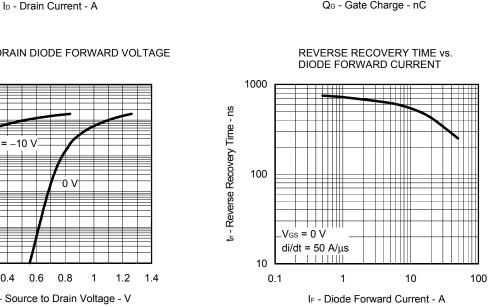
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE

CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



DYNAMIC INPUT/OUTPUT CHARACTERISTICS



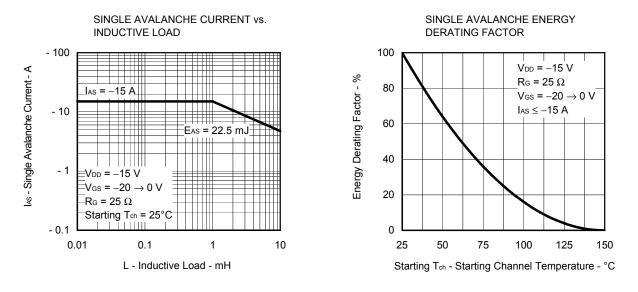


SOURCE TO DRAIN DIODE FORWARD VOLTAGE

-10

1000 Pulsed IF - Diode Forward Current - A 100 Vgs = -10 V 10 0 V 1 0.1 0.01 0.4 0 0.2 0.6 0.8 VF(S-D) - Source to Drain Voltage - V

Data Sheet G19279EJ1V0DS



ORDERING INFORMATION

PART NUMBER	LEAD PLATING	PACKING	PACKAGE	
μ PA2717AGR-E1-AT ^{Note}	Pure Sn (Tin)	Tape 2500 p/reel	Power SOP8	
μ PA2717AGR-E2-AT ^{Note}			0.08 g TYP.	

Note Pb-free (This product does not contain Pb in external electrode and other parts.)

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